

INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

2SD998

DESCRIPTION

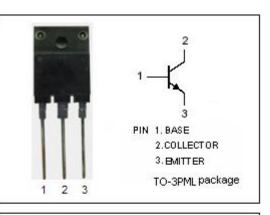
- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= 120V(Min)
- Good Linearity of h_{FE}
- Complement to Type 2SB778
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

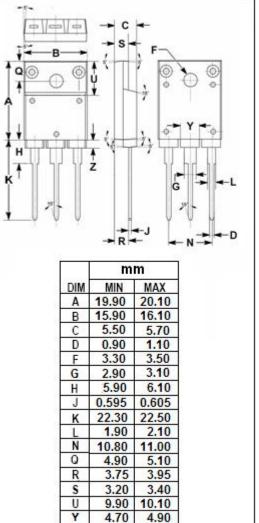
APPLICATIONS

- High power amplifier applications
- Recommend for 45-50W audio frequency amplifier output stage applications

ADSOLU	$ABSOLUTE MAXIMUM RATINGS(T_a=25 C)$					
SYMBOL	PARAMETER VALUE		UNIT			
V _{CBO}	Collector-Base Voltage 120		V			
V _{CEO}	Collector-Emitter Voltage	120	V			
V_{EBO}	EBO Emitter-Base Voltage		V			
lc	Collector Current-Continuous 10		A			
I _B	Base Current-Continuous	1	А			
Pc	Collector Power Dissipation $@ T_c=25^{\circ}C$		W			
TJ	Junction Temperature	150	°C			
T _{stg} Storage Temperature Range -5		-55~150	°C			

ABSOLUTE MAXIMUM RATINGS(T_a=25°C)





isc website: www.iscsemi.com

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1.90

2.10



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 50mA ; I _B = 0	120			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5.0A; I _B = 0.5A			2.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 5A ; V _{CE} = 5V			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 120V ; I _E = 0			10	μA
Іево	Emitter Cutoff Current	V _{ЕВ} = 5V; I _C = 0			10	μA
h _{FE}	DC Current Gain	I _C = 1A ; V _{CE} = 5V	55		160	
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V;f _{test} = 1.0MHz		170		pF
f⊤	Current-Gain—Bandwidth Product	Ic= 1A ; Vc= 5V		12		MHz

h_{FE} Classifications

R	ο	
55-110	80-160	

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